

Notice of References CitedApplication/Control No.
09/451,619Applicant(s)/Patent Under
Reexamination
MORI, SEIICHIExaminer
Howard WeissArt Unit
2814

Page 1 of 1

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*		Document Number	Date	Name	Classification	
		Country Code-Number-Kind Code	MM-YYYY			
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	C	US-5,631,179	05-1997	Sung et al.	438	264
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	"An EEPROM Cell with Asymmetrical Sidewall to Minimize Drain Couplings", April 1993, IBM technical Disclosure Bulletin, Vol. 36, No. 04, pp. 45-7
	V	Kume, H., et al., "A Flash-Erase EEPROM Cell with an Asymetric Source and Drain Structure", 1987, IEDM 87, pp. 560-3
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.